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Kind regards,

Team Nexperia

PDTC144V series

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 10 k Ω

Rev. 04 — 16 November 2009

Product data sheet

1. Product profile

1.1 General description

NPN resistor-equipped transistors.

Table 1. Product overview

Type number	Package	Package		
	NXP	JEITA		
PDTC144VE	SOT416	SC-75	PDTA144VE	
PDTC144VK	SOT346	SC-59A	PDTA144VK	
PDTC144VM	SOT883	SC-101	PDTA144VM	
PDTC144VS[1]	SOT54 (TO-92)	SC-43A	PDTA144VS	
PDTC144VT	SOT23	-	PDTA144VT	
PDTC144VU	SOT323	SC-70	PDTA144VU	

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- General-purpose switching and amplification
- Inverter and interface circuits

Circuit drivers

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
Io	output current (DC)		-	-	100	mA
R1	bias resistor 1 (input)		33	47	61	kΩ
R2/R1	bias resistor ratio		0.17	0.21	0.26	



2. Pinning information

Table 3. **Pinning** Pin **Description** Simplified outline **Symbol** SOT54 1 input (base) 2 output (collector) 3 GND (emitter) 001aab347 SOT54A 1 input (base) 2 output (collector) 3 GND (emitter) 001aab348 006aaa145 **SOT54** variant 1 input (base) 2 output (collector) 3 GND (emitter) 001aab447 006aaa145 SOT23, SOT323, SOT346, SOT416 1 input (base) 3 2 GND (emitter) 3 output (collector) 2 006aaa144 sym007 **SOT883** 1 input (base) 2 GND (emitter) 3 output (collector)

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NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 10 k Ω

Ordering information 3.

Ordering information Table 4.

Package						
Name	Description	Version				
SC-75	plastic surface mounted package; 3 leads	SOT416				
SC-59A	plastic surface mounted package; 3 leads	SOT346				
SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883				
SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54				
-	plastic surface mounted package; 3 leads	SOT23				
SC-70	plastic surface mounted package; 3 leads	SOT323				
	Name SC-75 SC-59A SC-101 SC-43A	Name Description SC-75 plastic surface mounted package; 3 leads SC-59A plastic surface mounted package; 3 leads SC-101 leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm SC-43A plastic single-ended leaded (through hole) package; 3 leads - plastic surface mounted package; 3 leads				

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

Marking

Table 5. Marking codes

Table of Historia	
Type number	Marking code ^[1]
PDTC144VE	18
PDTC144VK	29
PDTC144VM	G6
PDTC144VS	TC144V
PDTC144VT	*AA
PDTC144VU	*18

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	50	V
V_{CEO}	collector-emitter voltage	open base	-	50	V
V_{EBO}	emitter-base voltage	open collector	-	15	V
VI	input voltage				
	positive		-	+40	V
	negative		-	-15	V
I _O	output current (DC)		-	100	mA
I _{CM}	peak collector current		-	100	mA
P _{tot}	total power dissipation				
	SOT416	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> -	150	mW
	SOT346	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> -	250	mW
	SOT883	$T_{amb} \le 25 ^{\circ}C$	[2][3]	250	mW
	SOT54	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> -	500	mW
	SOT23	$T_{amb} \le 25 ^{\circ}C$	[1] -	250	mW
	SOT323	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> -	200	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

^[1] Refer to standard mounting conditions.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> _	-	833	K/W
	SOT346		<u>[1]</u> _	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> _	-	250	K/W
	SOT23		<u>[1]</u> _	-	500	K/W
	SOT323		<u>[1]</u> _	-	625	K/W

^[1] Refer to standard mounting conditions.

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^[2] Reflow soldering is the only recommended soldering method.

^[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 µm copper strip line.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Refer to SOT883 standard mounting conditions; FR4 printed-circuit board with 60 μm copper strip line.

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NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 10 k Ω

Characteristics

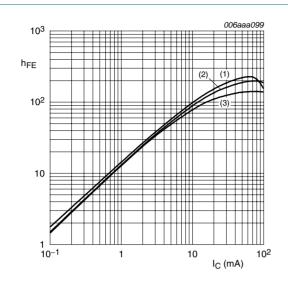
Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I _{CEO}	collector-emitter	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	1	μΑ
	cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	150	μΑ
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}$	-	3.1	1	V
V _{I(on)}	on-state input voltage	$V_{CE} = 300 \text{ mV}; I_{C} = 2 \text{ mA}$	6	3.8	-	V
R1	bias resistor 1 (input)		33	47	61	kΩ
R2/R1	bias resistor ratio		0.17	0.21	0.26	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	2	pF

006aaa100

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 10 k Ω

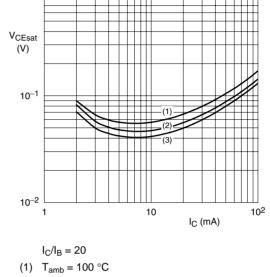


$$V_{CE} = 5 V$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

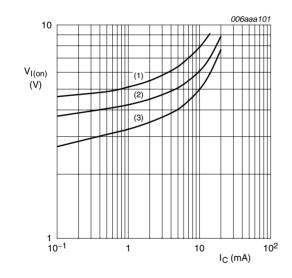
Fig 1. DC current gain as a function of collector current; typical values



(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values



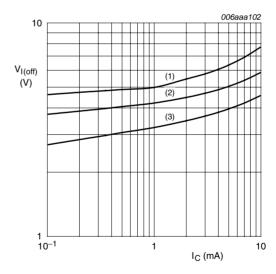
$$V_{CE} = 0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 3. On-state input voltage as a function of collector current; typical values



$$V_{CE} = 5 V$$

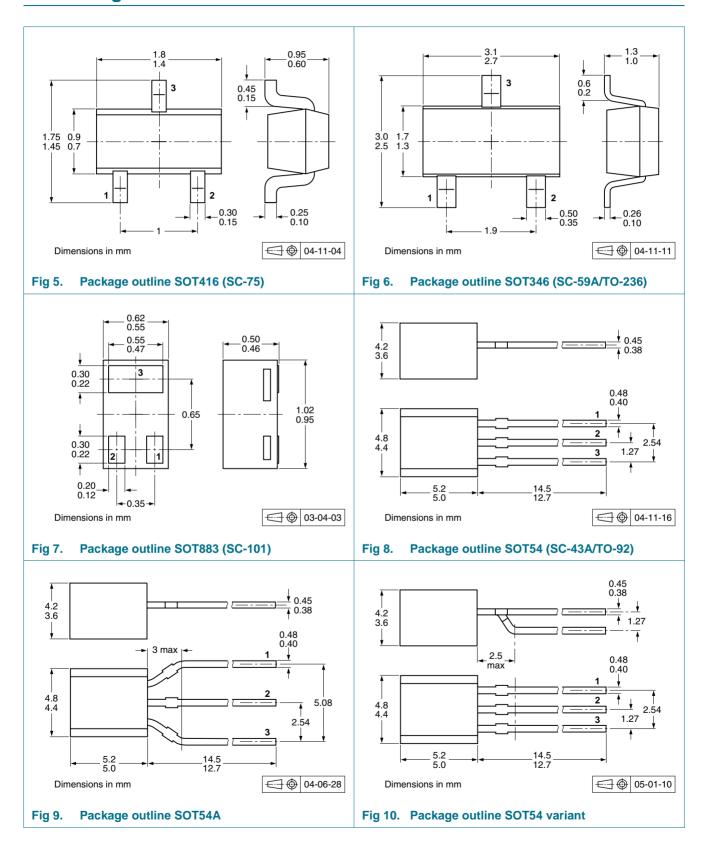
(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

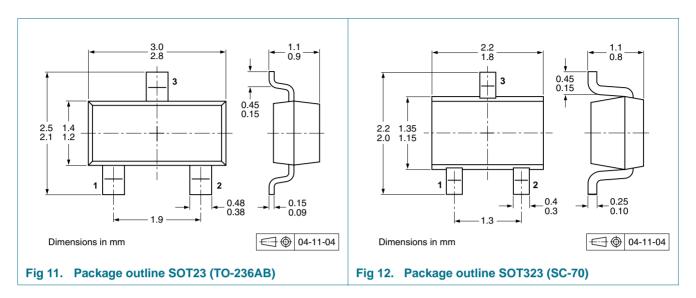
(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig 4. Off-state input voltage as a function of collector current; typical values

8. Package outline



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9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing q	Packing quantity			
			3000	5000	10000		
PDTC144VE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135		
PDTC144VK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135		
PDTC144VM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315		
PDTC144VS	SOT54	bulk, straight leads	-	-412	-		
	SOT54A	tape and reel, wide pitch	-	-	-116		
		tape ammopack, wide pitch	-	-	-126		
	SOT54 variant	bulk, delta pinning	-	-112	-		
PDTC144VT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235		
PDTC144VU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135		

^[1] For further information and the availability of packing methods, see Section 12.

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NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 10 k Ω

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTC144V_SER_4	20091116	Product data sheet	-	PDTC144V_SER_3
Modifications:		eet was changed to reflect t w legal definitions and discl		
PDTC144V_SER_3	20050215	Product data sheet	-	PDTC144VT_2
PDTC144VT_2	20040511	Objective data sheet	-	PDTC144VT_1
PDTC144VT_1	20040305	Objective data sheet	_	_

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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12. Contact information

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PDTC144V series

NPN resistor-equipped transistors; R1 = 47 k Ω , R2 = 10 k Ω

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Date of release: 16 November 2009 Document identifier: PDTC144V_SER_4

